

Extending DRSEM inspection capacities and Applications with the Introduction of D2DB Technology

HPO Center

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D2DB



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01

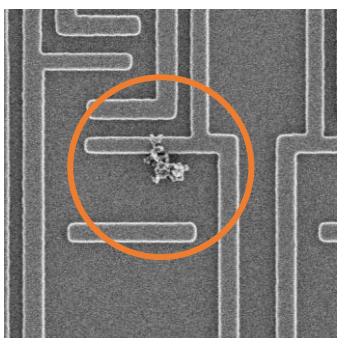
PART ONE

Overview

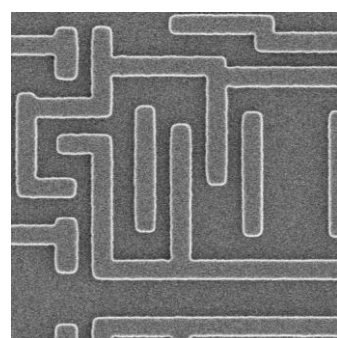


Challenge for Defect Review

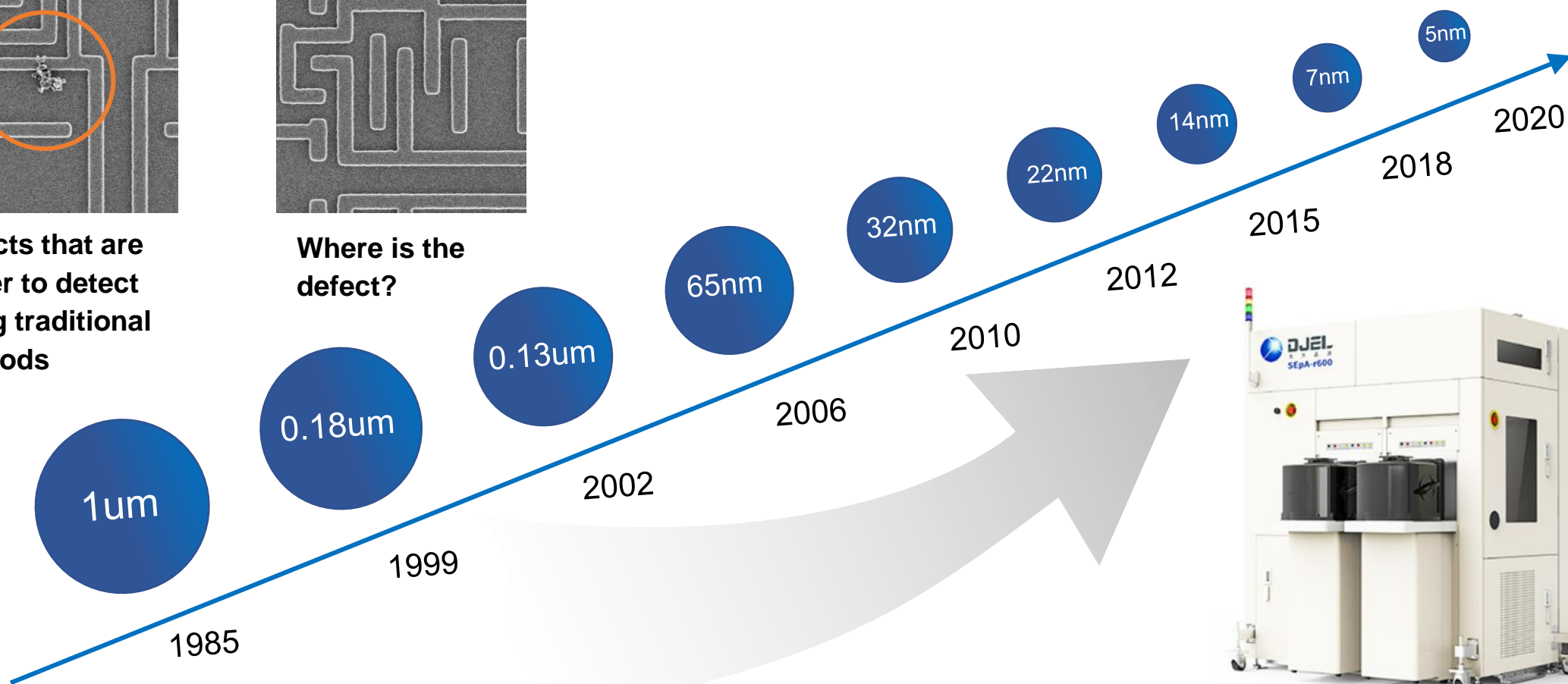
DRSEM equipment advances should be accompanied by advanced defect detection algorithms.



Defects that are easier to detect using traditional methods

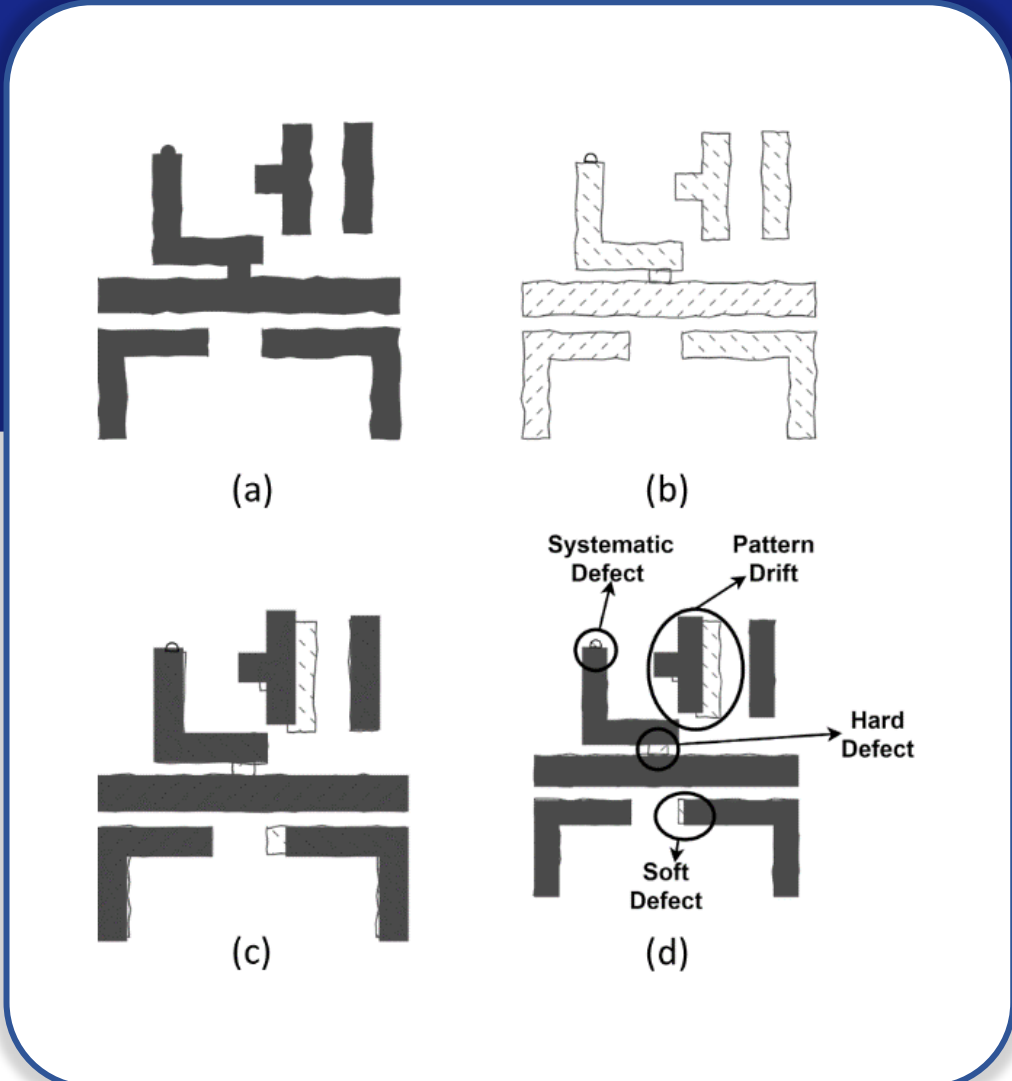


Where is the defect?

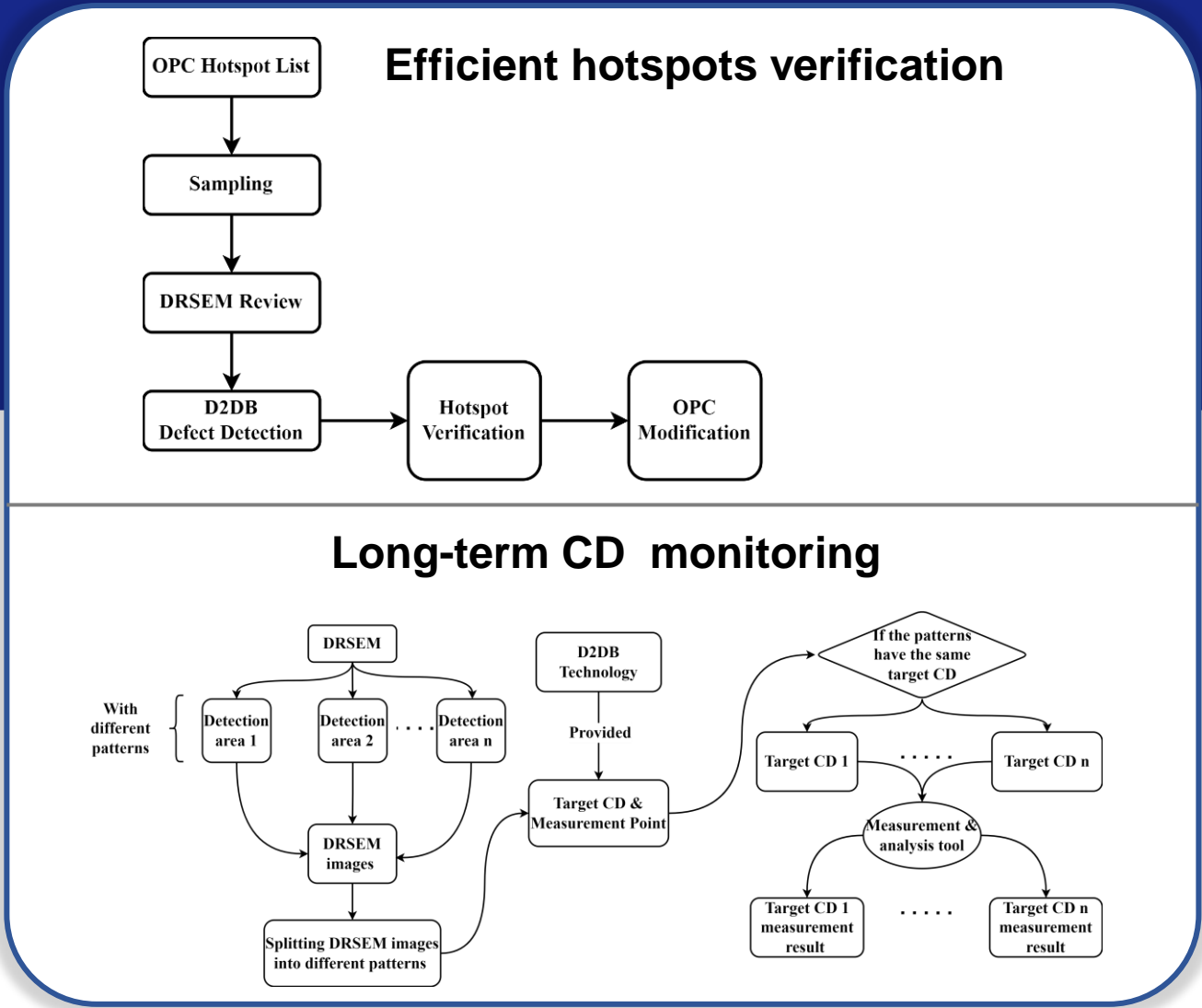




Defect detectability enhancement



Application extension





02

PART TWO

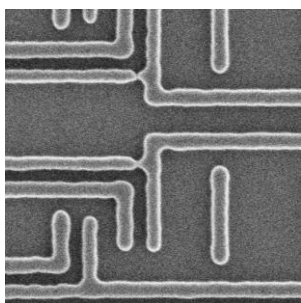
DJEL D2DB

Workflow

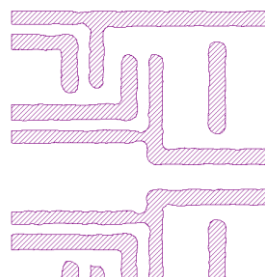


This workflow has been validated on both test wafers and production wafers

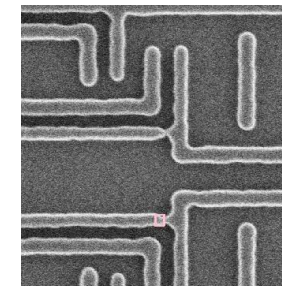
Image Acquisition



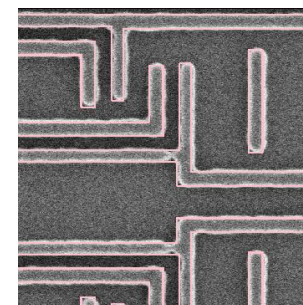
Contour Extraction



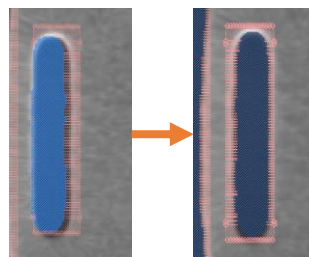
Defect Detection



Alignment Image with Design



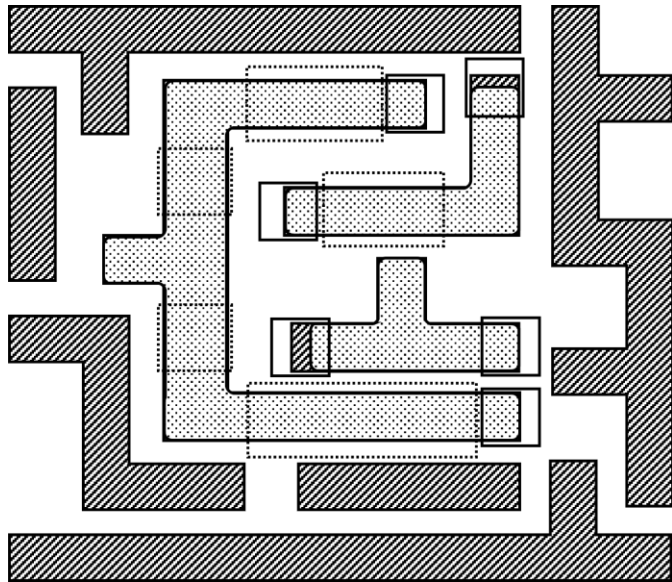
Data Pre-processing



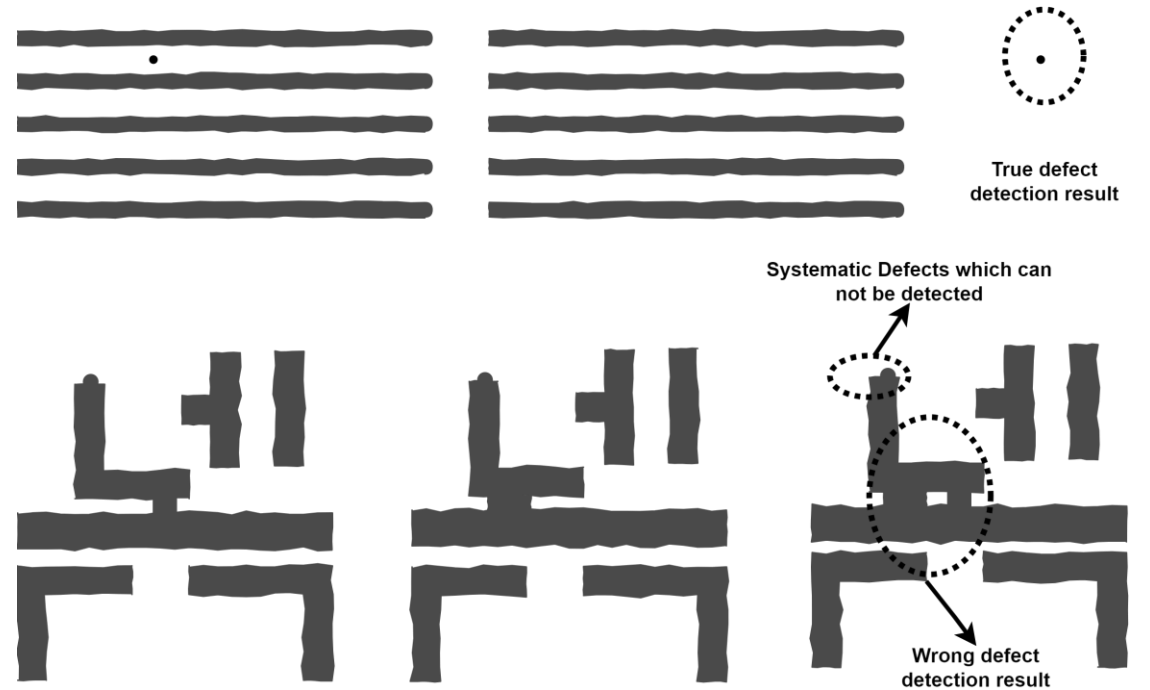


Detectability Enhancements

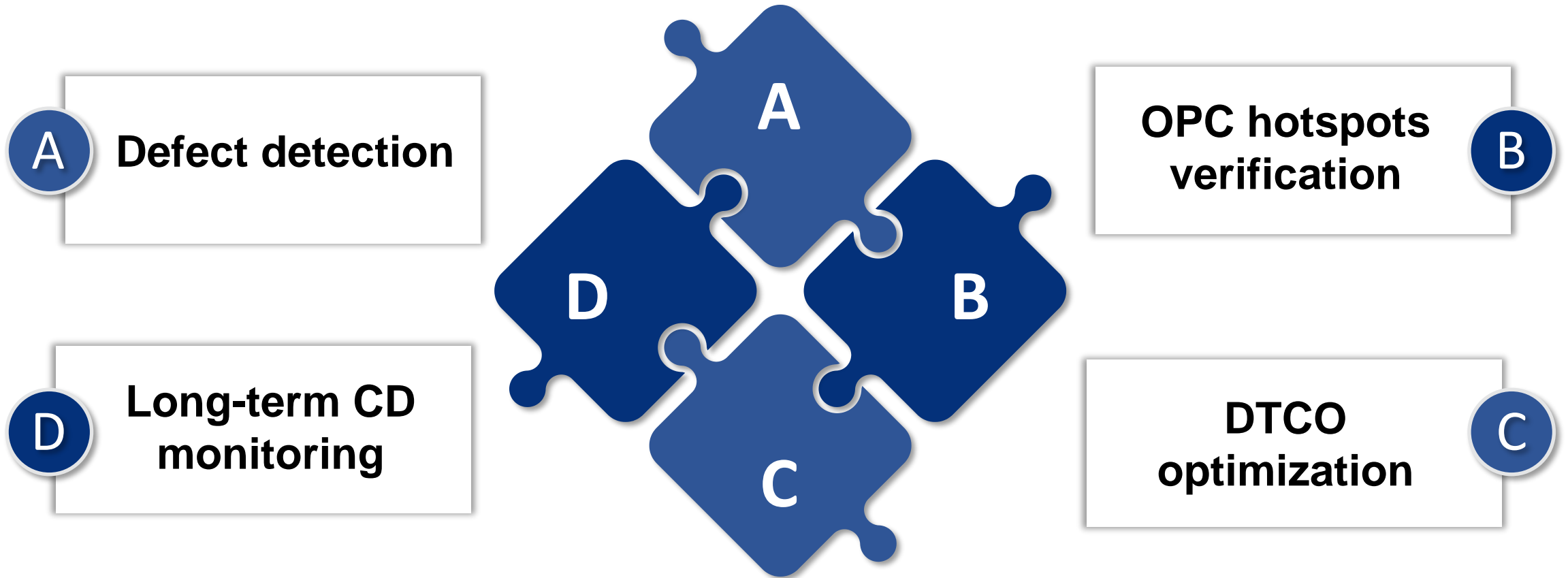
Using the design layout as a golden reference, even the tiniest EPE can be detected.



D2DB is able to detect defects repeated on dies and shoots, which are often missed by the D2D method.



DJEL D2DB Application Scenarios





03

PART Three

Experiment Results



Experimental Workflow

A

- Hotspot List Generation
- DRSEM Image Acquisition
- D2DB Defect Detection

B

Image Pre-Processing

- Image rotation and distortion correction for the DRSEM images

C

Defect Detectors

- Types: End/CD variation/pinch/bridge/complex pattern



The table lists only a part of the criteria for defect detection. Setting recipe parameter is still a challenge for users who are not familiar with the design layout data.

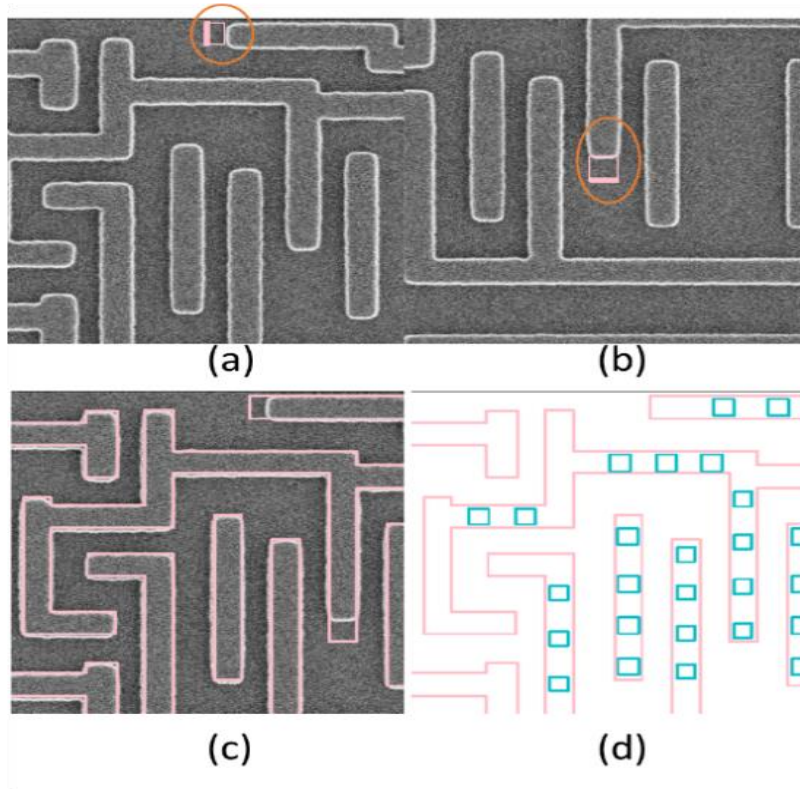
Detectors	Detection threshold
End	$\leq -30 \text{ nm}$ or $\geq 30 \text{ nm}$
Line width	$\leq -1.5 \text{ ratio}$ or $\geq 1.5 \text{ ratio}$
Pinch	$\leq 50 \text{ nm}$
Bridge	$\leq 60 \text{ nm}$
2D Complex pattern	$\leq 0.6 \text{ ratio}$ or $\geq 1.2 \text{ ratio}$



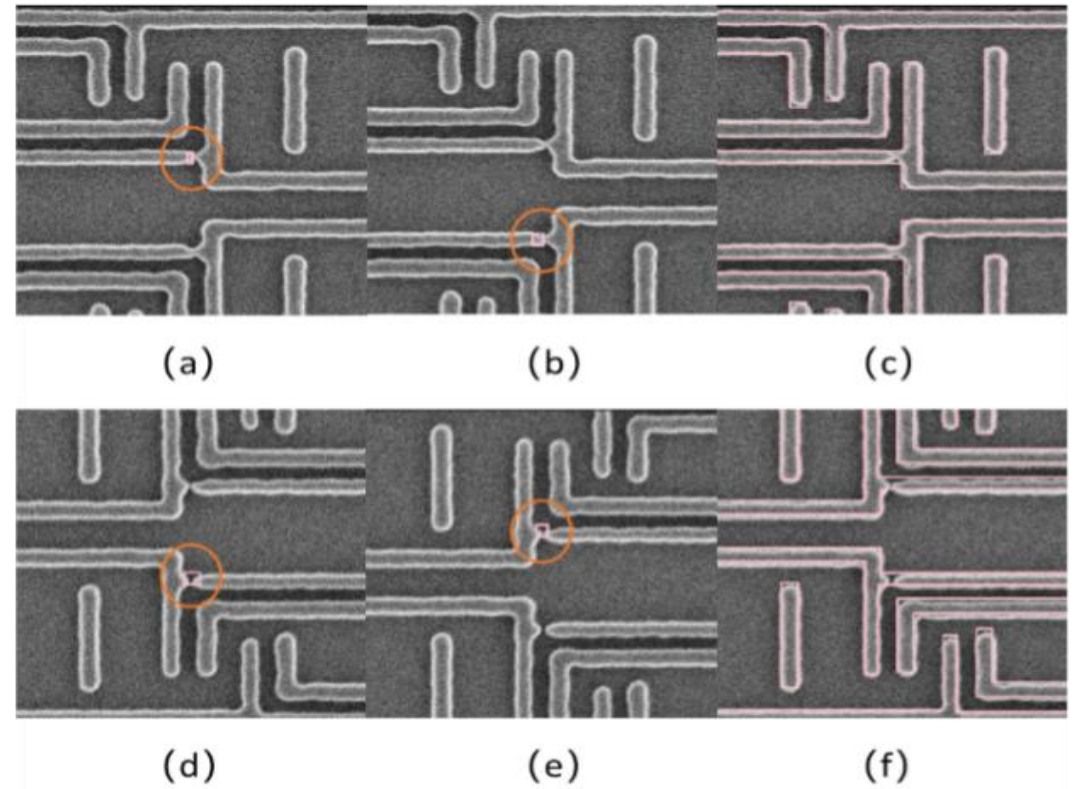
Detectability Enhancements

End pullback defects are detected on simple patterned areas.

Defect classification using multi-layer design data enables correct risk ranking.



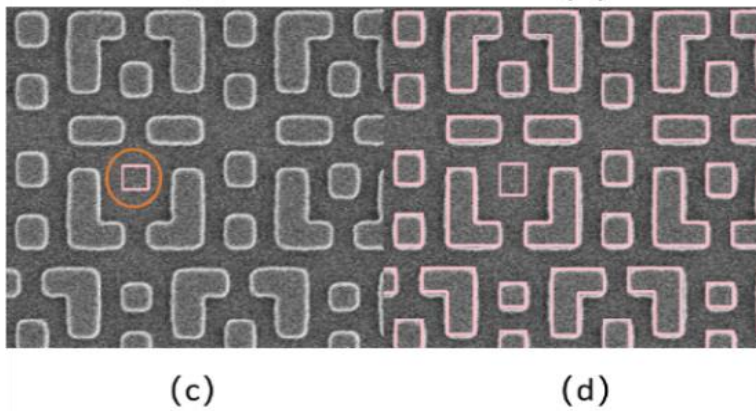
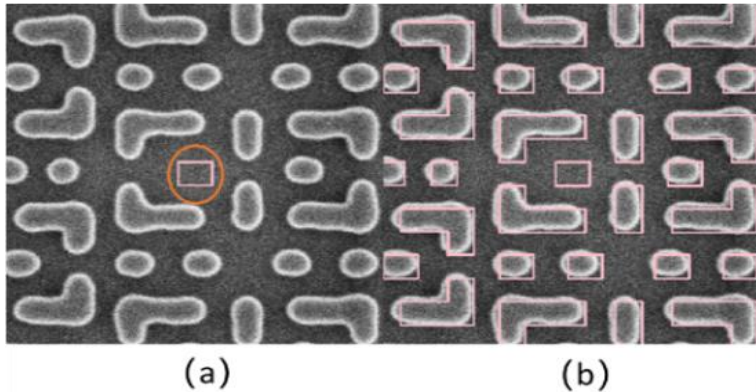
Pinch defects are detected on complex patterned areas, which are often misclassified as bridges without design layout data.



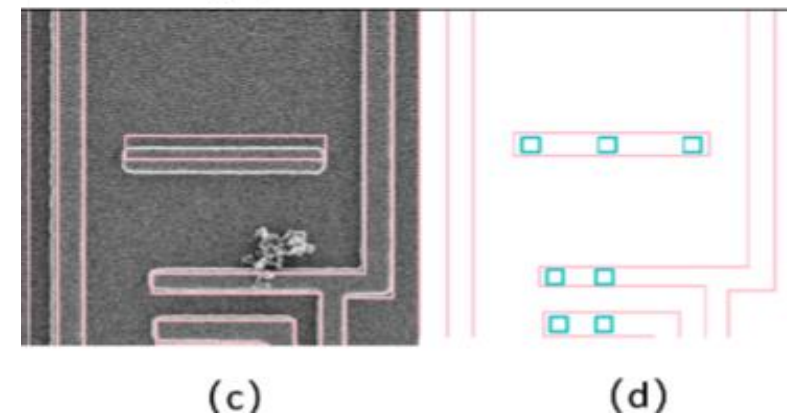
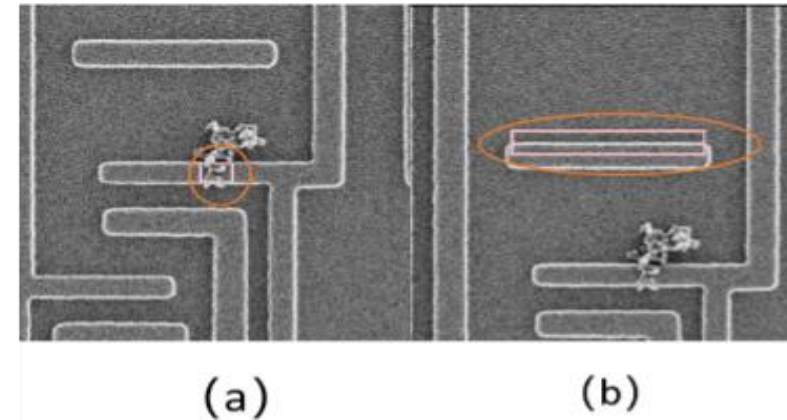


Detectability Enhancements

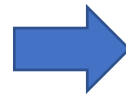
Missing patterns on SRAM areas are detected without false defect detection.



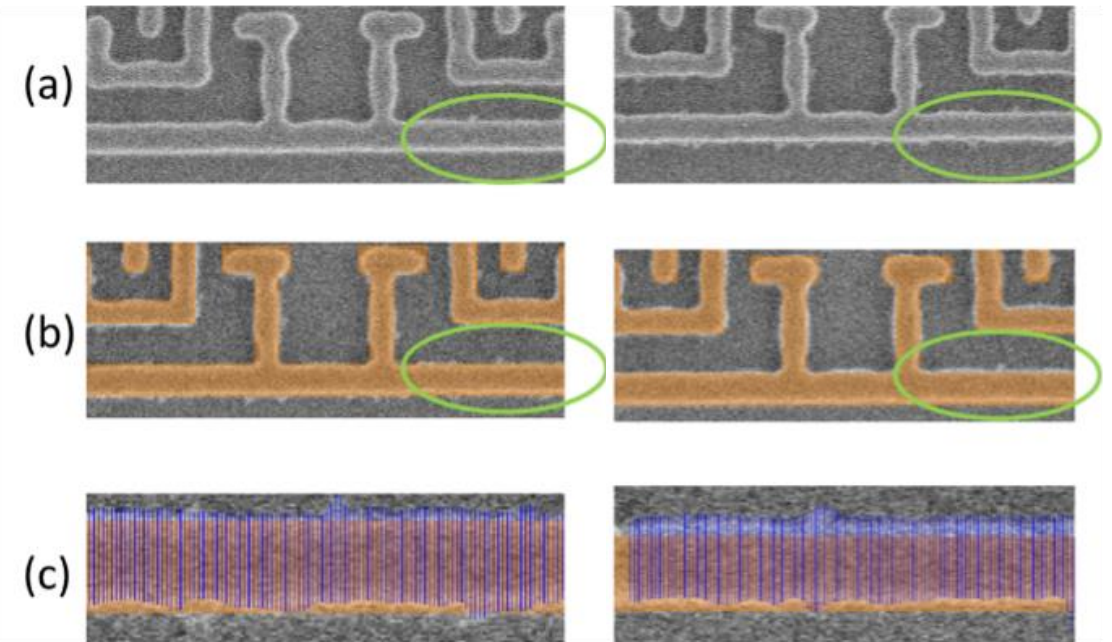
Both particle and pattern drift defects are detected and correctly classified.



- D2DB can also collect CD data on real 2D patterned areas.
- Different from the CD data on CD-SEM, the CD variation on real patterns is much greater than on test patterns.
- These data are more suitable for long-term CD monitoring.



CD Measurements





Validation on Production Wafers

- Image count :4600
- Image FOV: 3um
- Image size: 720 x 720

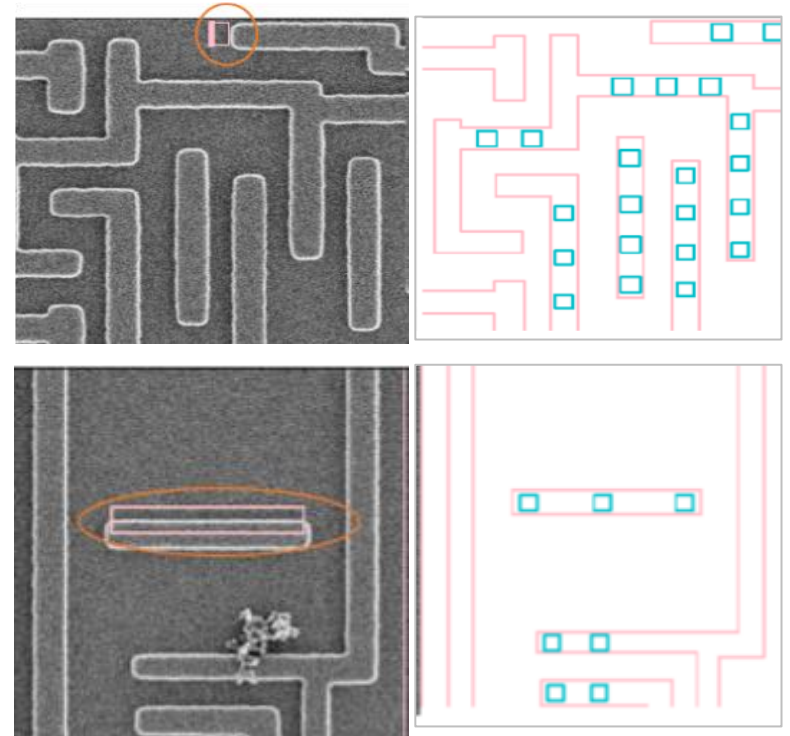
- CPU count: x64 cores
- Time Consumption: ~3 hours



- ✓ End pullback: 59 (nonkiller)
- ✓ Bridge: 176 (killer)
- ✓ Peeling: 2 (killer)

DJEL D2DB Method

- ✓ Capture killer defects and soft defects
- ✓ Utilize multi-layer design info
- ✓ Filter fake defects
- ✓ High throughput



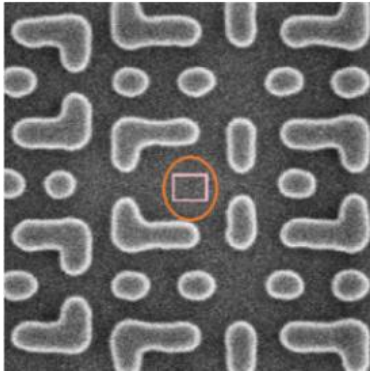
* Defect Type Samples (not the defects on production wafers)



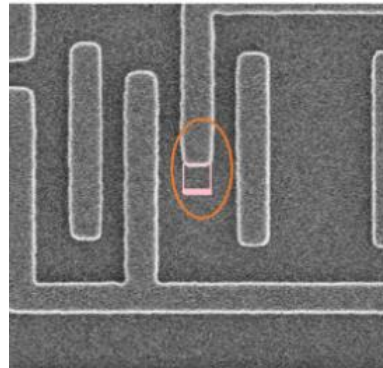
D2DB Assists Defect Classification

Use of different detectors and design layout information to identify defect types

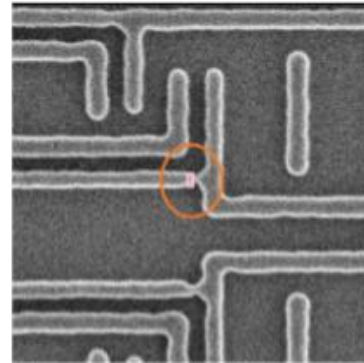
Missing



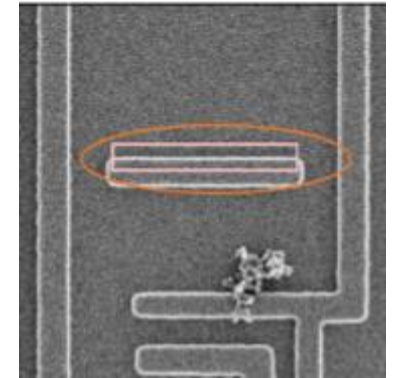
End Pullback



Pinch

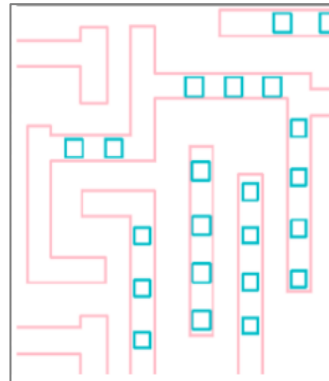
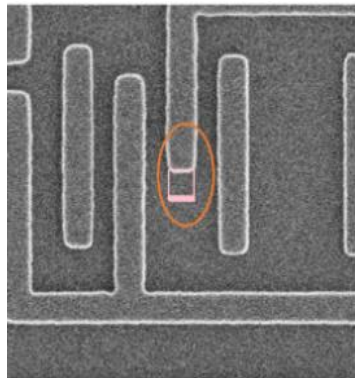


Pattern Drift

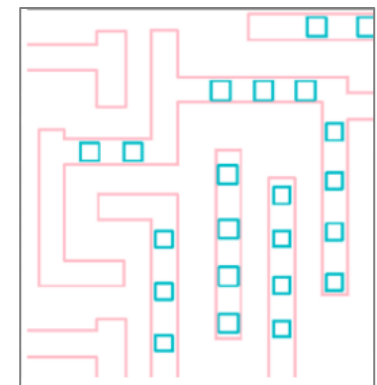
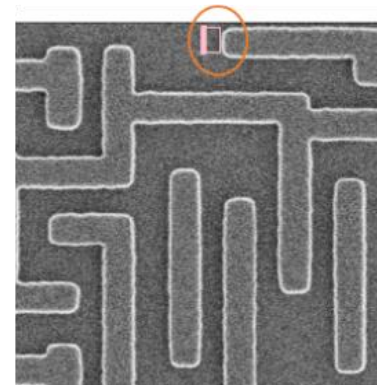


Using multi-layer information to capture critical defects

Critical



Uncritical



Verification

- DJEL D2DB flow is validated on both test wafers and production wafers.

Application Scenarios Expansion

- DJEL D2DB method can be used for OPC hotspot validation and long-term CD monitoring on production chip patterns.

Detection enhancement

- The D2DB approach improved the defect detectability of the DRSEM.

Multi-layout advantages

- D2DB offers advantages in defect filtering and classification by using design layout information.



Conclusion

THANKS ALL



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